

DualCool™ N-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD16322Q5C](#)

FEATURES

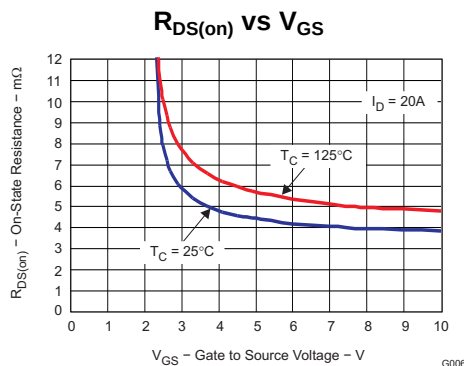
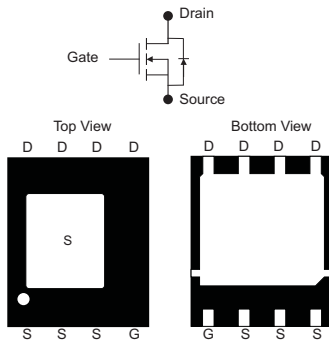
- DualCool™ Package SON 5×6mm
- Optimized for Two Sided Cooling
- Optimized for 5V Gate Drive
- Ultralow Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant and Halogen Free

APPLICATIONS

- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems
- Optimized for Synchronous or Control FET Applications

DESCRIPTION

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.



PRODUCT SUMMARY

V_{DS}	Drain to Source Voltage	25	V
Q_g	Gate Charge Total (4.5V)	6.8	nC
Q_{gd}	Gate Charge Gate to Drain	1.3	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 3V$	5.4 mΩ
		$V_{GS} = 4.5V$	4.6 mΩ
		$V_{GS} = 8V$	3.9 mΩ
$V_{GS(th)}$	Threshold Voltage	1.1	V

ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16322Q5C	SON 5x6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

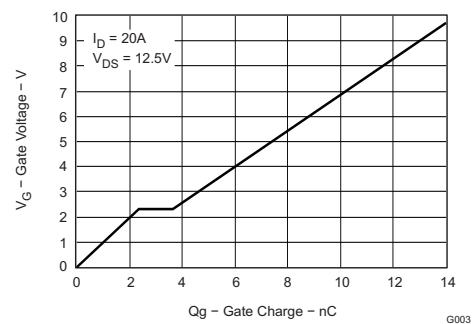
ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
V_{DS}	Drain to Source Voltage	25	V
V_{GS}	Gate to Source Voltage	+10 / -8	V
I_D	Continuous Drain Current, $T_C = 25^\circ\text{C}$	97	A
	Continuous Drain Current ⁽¹⁾	21	A
I_{DM}	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾	136	A
P_D	Power Dissipation ⁽¹⁾	3.1	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
E_{AS}	Avalanche Energy, single pulse $I_D = 50A, L = 0.1mH, R_G = 25\Omega$	125	mJ

(1) $R_{\theta JA} = 39^\circ\text{C/W}$ on 1-inch² Cu, (2-oz.) on a 0.06" thick FR4 PCB.

(2) Pulse duration $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$

Gate Charge



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Static Characteristics							
B _{DSS}	Drain to Source Voltage	V _{GS} = 0V, I _{DS} = 250μA	25			V	
I _{DSS}	Drain to Source Leakage	V _{GS} = 0V, V _{DS} = 20V	1			μA	
I _{GSS}	Gate to Source Leakage	V _{DS} = 0V, V _{GS} = +10/−8V	100			nA	
V _{GS(th)}	Gate to Source Threshold Voltage	V _{DS} = V _{GS} , I _D = 250μA	0.9	1.1	1.4	V	
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 3V, I _{DS} = 20A	5.4			7	mΩ
		V _{GS} = 4.5V, I _{DS} = 20A	4.6			5.8	mΩ
		V _{GS} = 8V, I _{DS} = 20A	3.9			5	mΩ
g _{fs}	Transconductance	V _{DS} = 15V, I _{DS} = 20A	106			S	
Dynamic Characteristics							
C _{iss}	Input Capacitance	V _{GS} = 0V, V _{DS} = 12.5V, f = 1MHz	1050	1365	pF		
C _{oss}	Output Capacitance		740	950	pF		
C _{rss}	Reverse Transfer Capacitance		55	70	pF		
R _G	Series Gate Resistance		1.1	2.2	Ω		
Q _g	Gate Charge Total (4.5V)	V _{DS} = 12.5V, I _{DS} = 20A	6.8	9.7	nC		
Q _{gd}	Gate Charge – Gate to Drain		1.3	nC			
Q _{gs}	Gate Charge – Gate to Source		2.4	nC			
Q _{g(th)}	Gate Charge at V _{th}		1.3	nC			
Q _{oss}	Output Charge	V _{DS} = 13V, V _{GS} = 0V	17	nC			
t _{d(on)}	Turn On Delay Time	V _{DS} = 12.5V, V _{GS} = 4.5V, I _{DS} = 20A, R _G =2Ω	6.1	ns			
t _r	Rise Time		10.7	ns			
t _{d(off)}	Turn Off Delay Time		12.3	ns			
t _f	Fall Time		3.7	ns			
Diode Characteristics							
V _{SD}	Diode Forward Voltage	I _{DS} = 20A, V _{GS} = 0V	0.8	1	V		
Q _{rr}	Reverse Recovery Charge	V _{DD} = 13V, I _F = 20A, di/dt = 300A/μs	19	nC			
t _{rr}	Reverse Recovery Time		21	ns			

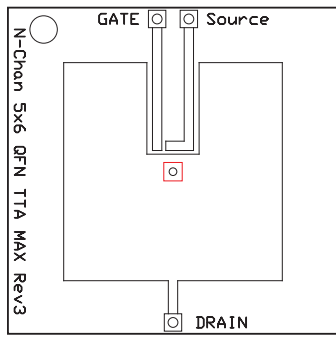
THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
R _{θJC}	Thermal Resistance Junction to Case (Top Source) ⁽¹⁾			3.5	°C/W
R _{θJC}	Thermal Resistance Junction to Case (Bottom drain) ⁽¹⁾			2.4	°C/W
R _{θJA}	Thermal Resistance Junction to Ambient ⁽¹⁾⁽²⁾			50	°C/W

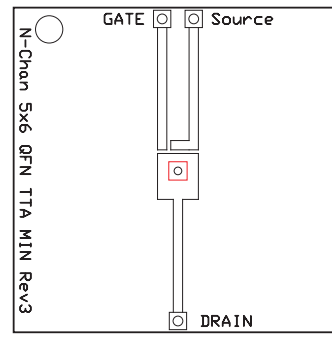
(1) R_{θJC} is determined with the device mounted on a 1-inch² 2-oz. Cu pad on a 1.5 × 1.5-inch 0.06-inch thick FR4 board. R_{θJC} is specified by design, whereas R_{θCA} is determined by the user's board design.

(2) Device mounted on FR4 material with 1-inch² of 2-oz. Cu.



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Max $R_{\theta JA} = 50^{\circ}\text{C/W}$
when mounted on
1 inch² of 2-oz. Cu.

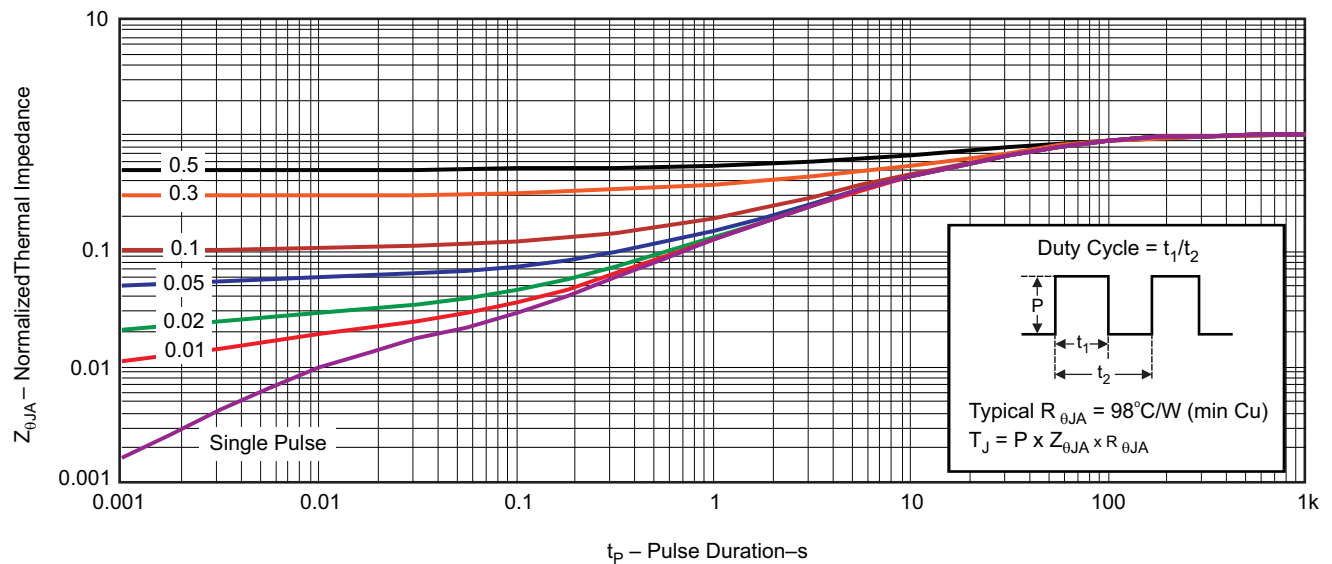


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Max $R_{\theta JA} = 123^{\circ}\text{C/W}$
when mounted on
minimum pad area of
2-oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

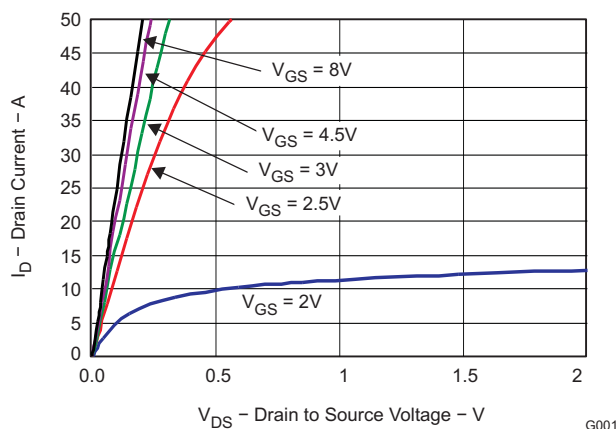


Figure 2. Saturation Characteristics

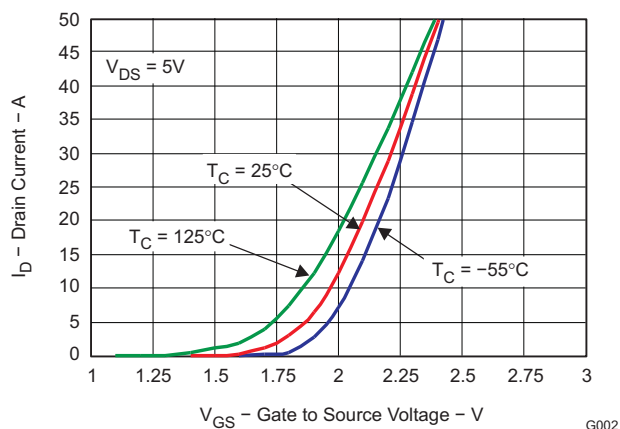


Figure 3. Transfer Characteristics

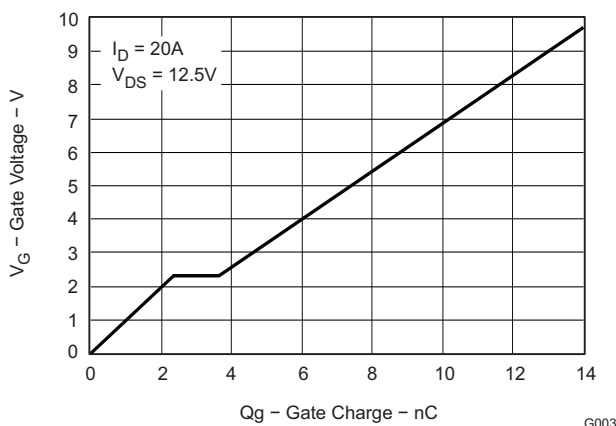


Figure 4. Gate Charge

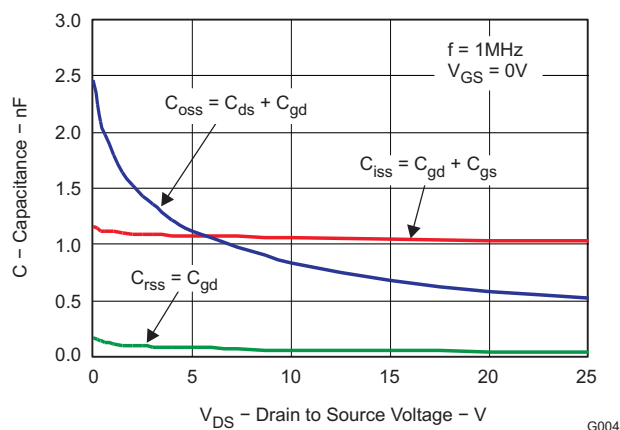


Figure 5. Capacitance

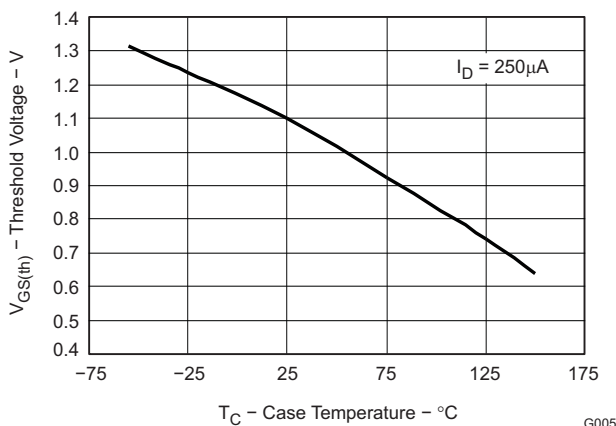


Figure 6. Threshold Voltage vs. Temperature

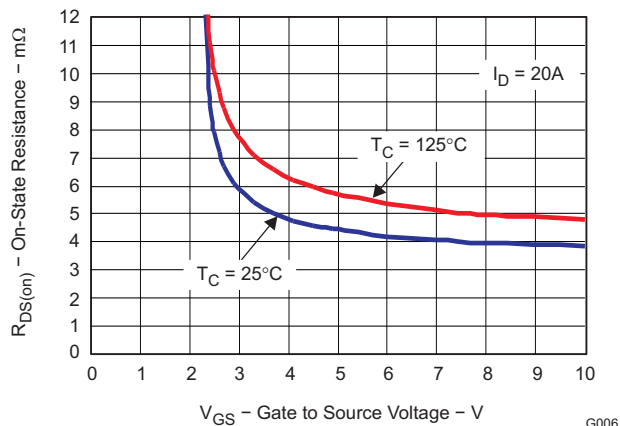


Figure 7. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

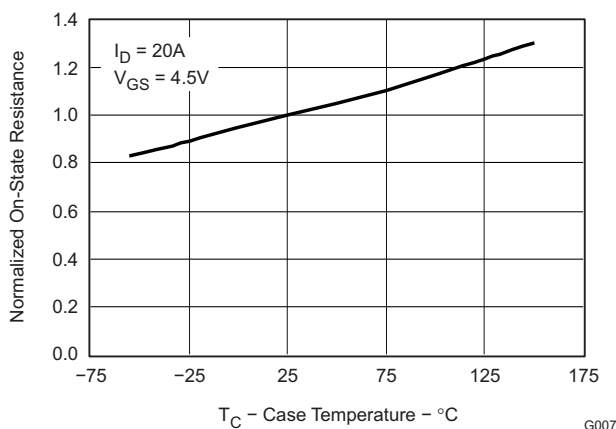


Figure 8. On Resistance vs. Temperature

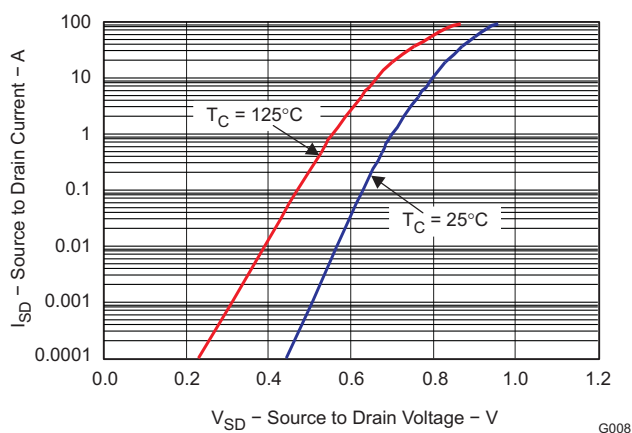


Figure 9. Typical Diode Forward Voltage

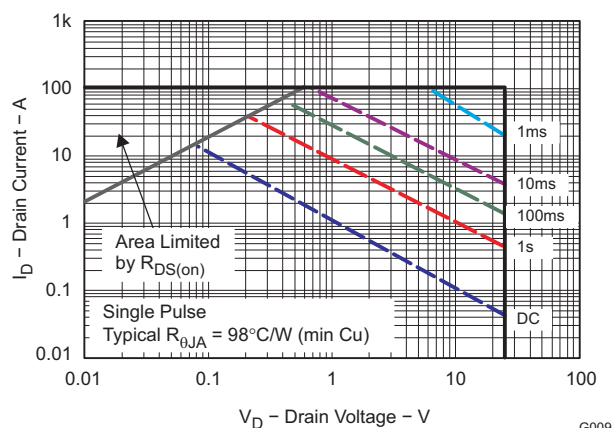


Figure 10. Maximum Safe Operating Area

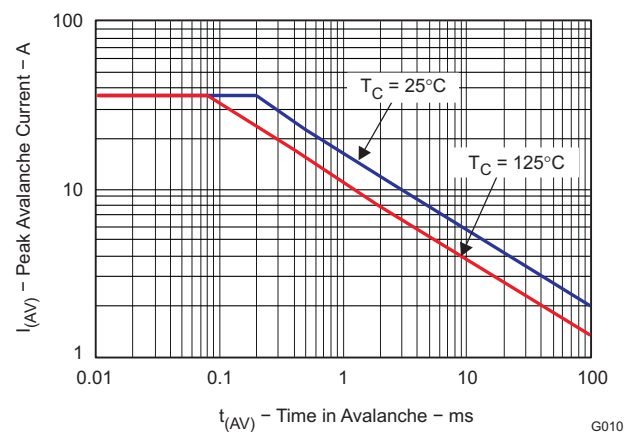


Figure 11. Single Pulse Unclamped Inductive Switching

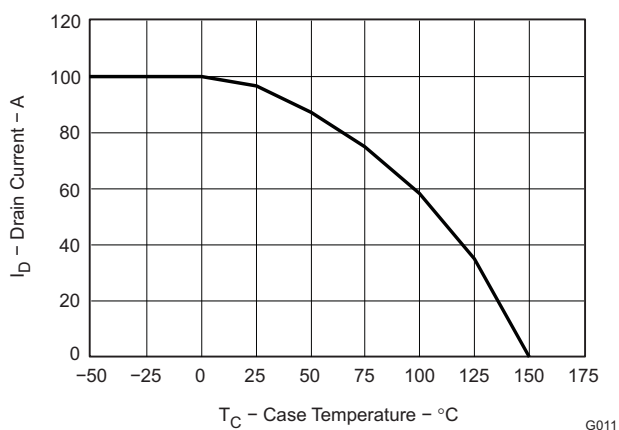
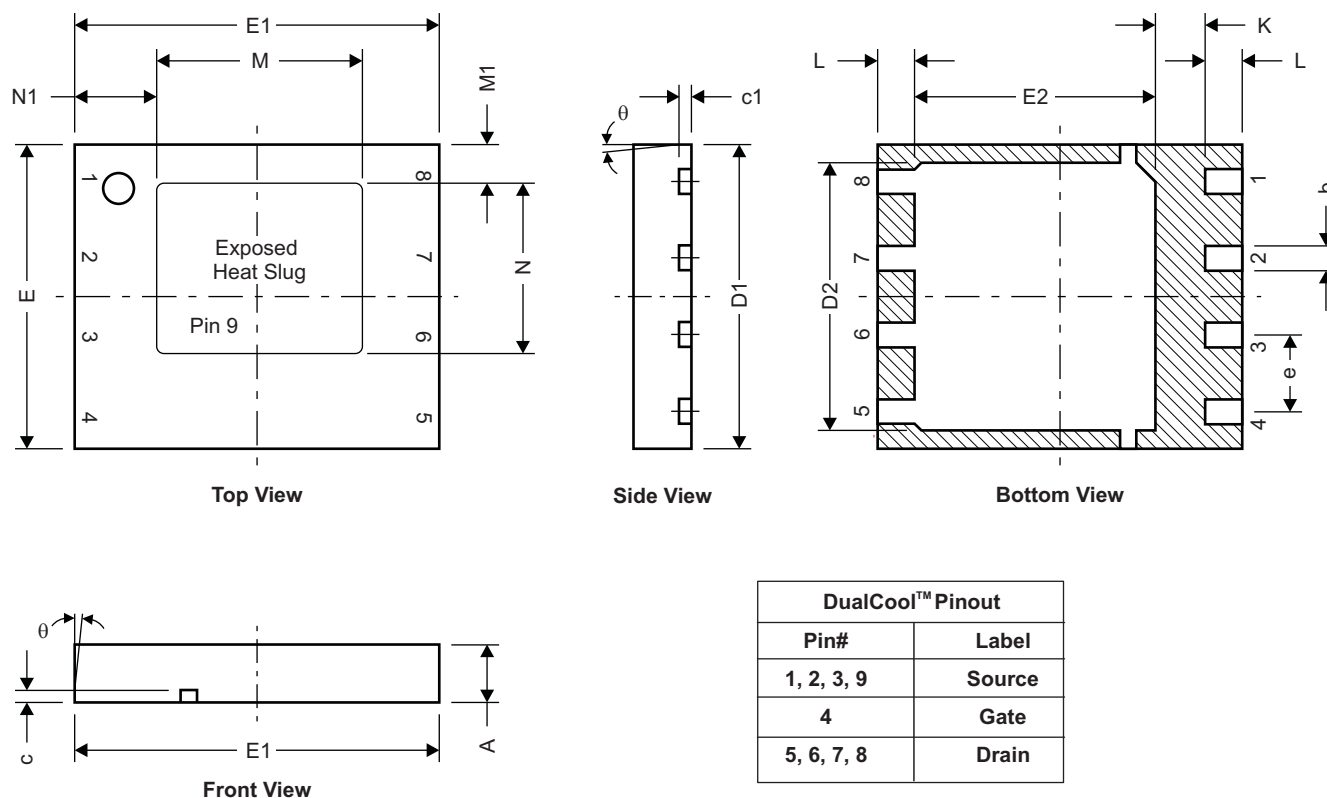


Figure 12. Maximum Drain Current vs. Temperature

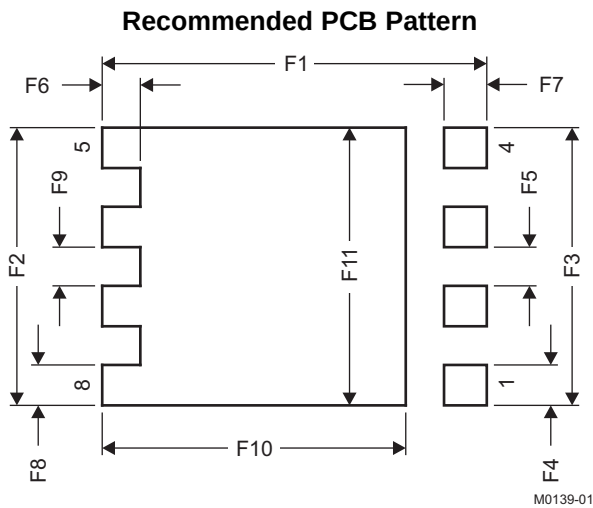
MECHANICAL DATA

Q5C Package Dimensions



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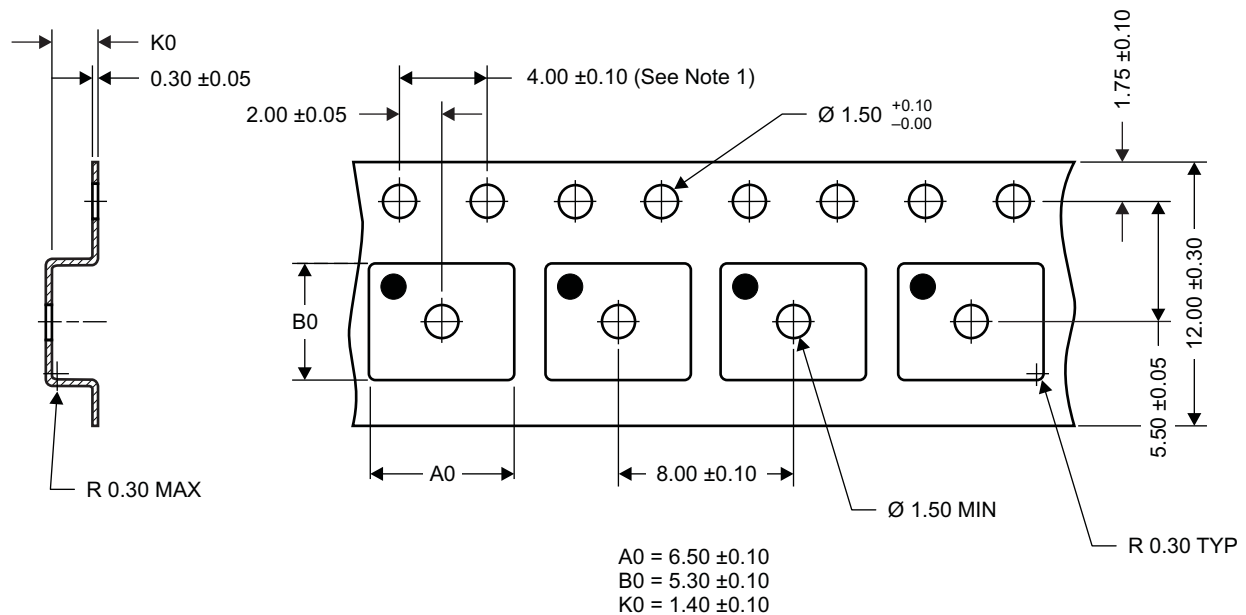
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 TYP		0.050	
L	0.510	0.710	0.020	0.028
θ	–	–	–	–
K	0.760	–	0.030	–
M	3.260	3.460	0.128	0.136
M1	0.520	0.720	0.020	0.028
N	2.720	2.920	0.107	0.115
N1	1.227	1.427	0.048	0.056



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q5C Tape and Reel Information



Notes:

- 10-sprocket hole-pitch cumulative tolerance ± 0.2
- Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- Material: black static-dissipative polystyrene
- All dimensions are in mm, unless otherwise specified.
- A0 and B0 measured on a plane 0.3mm above the bottom of the pocket
- MSL1 260°C (IR and convection) PbF reflow compatible

Package Marking Information

Location

1st Line

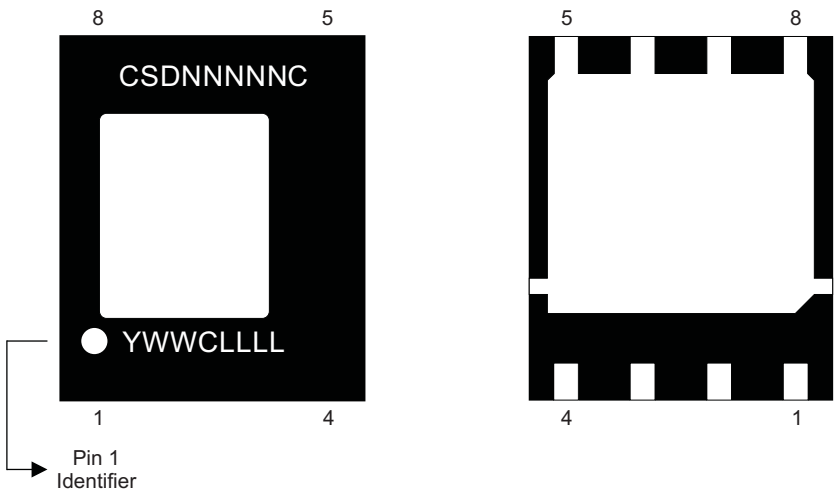
CSD = Fixed Characters
NNNNN = 5-digit Product Code
C = DualCool Package

2nd Line (Date Code)

Y = Last digit of the Year
WW = 2-digit Work Week
C = Country of Origin
> Philippines = P
> Taiwan = T
> China = C

3rd Line

LLLL = Last 4 digits of the Wafer Lot Number



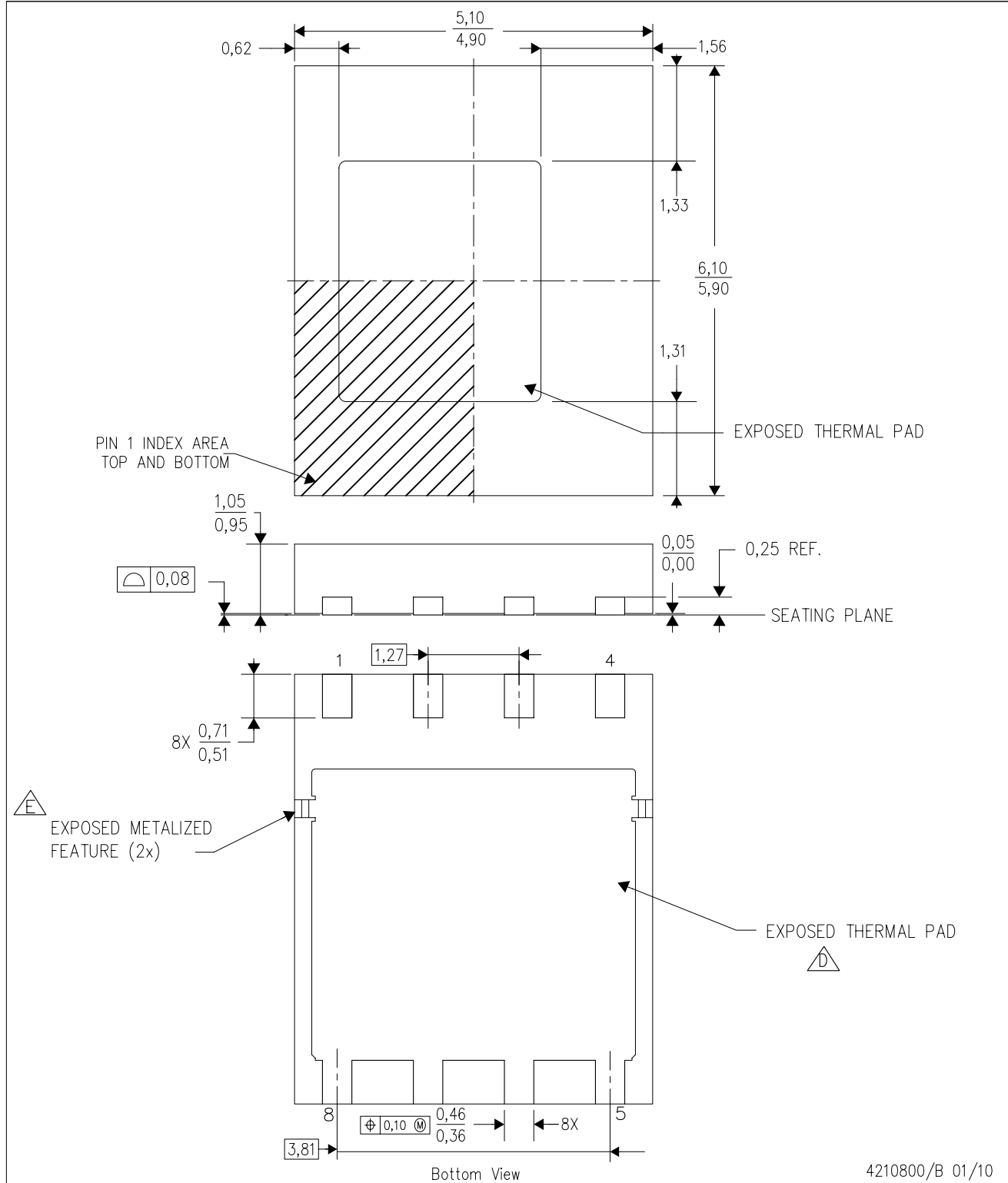
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REVISION HISTORY

Changes from Original (December 2009) to Revision A	Page
• Changed the labels on the Bottom View pinout image	1
• Changed the Mechanical Data dimensions table. Added dimensions for M, M1, N and N1	6

DQU (R-PSO-N8)

PLASTIC SMALL OUTLINE NO-LEAD



4210800/B 01/10

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Dual Cool No-Lead (SON) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - Metalized features are supplier options and may not be on the package.

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